

# HiPerFRED<sup>2</sup>

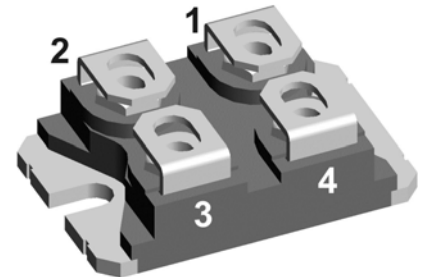
preliminary

$$\begin{aligned} V_{RRM} &= 200V \\ I_{FAV} &= 2 \times 120A \\ t_{rr} &= 55ns \end{aligned}$$

High Performance Fast Recovery Diode  
Low Loss and Soft Recovery  
Parallel legs

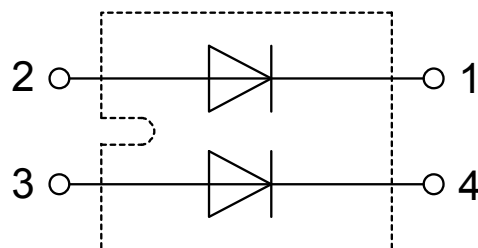
Part number

**DPF240X200NA**



Backside: isolated

 E72873



## Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low  $I_{rm}$ -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{rm}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

## Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

## Package: SOT-227B (minibloc)

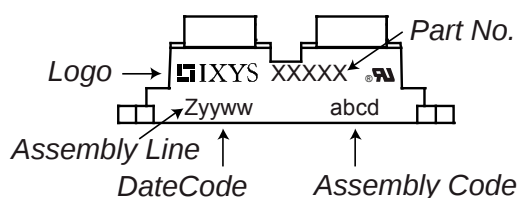
- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Base plate: Copper internally DCB isolated
- Advanced power cycling

| Fast Diode        |                                              |                                                                                     |                         | Ratings                 |      |      |      |
|-------------------|----------------------------------------------|-------------------------------------------------------------------------------------|-------------------------|-------------------------|------|------|------|
| Symbol            | Definition                                   | Conditions                                                                          |                         | min.                    | typ. | max. | Unit |
| V <sub>RSM</sub>  | max. non-repetitive reverse blocking voltage | T <sub>VJ</sub> = 25°C                                                              |                         |                         |      | 200  | V    |
| V <sub>RRM</sub>  | max. repetitive reverse blocking voltage     | T <sub>VJ</sub> = 25°C                                                              |                         |                         |      | 200  | V    |
| I <sub>R</sub>    | reverse current, drain current               | V <sub>R</sub> = 200 V                                                              | T <sub>VJ</sub> = 25°C  |                         |      | 10   | μA   |
|                   |                                              | V <sub>R</sub> = 200 V                                                              | T <sub>VJ</sub> = 150°C |                         |      | 0.5  | mA   |
| V <sub>F</sub>    | forward voltage drop                         | I <sub>F</sub> = 120 A                                                              | T <sub>VJ</sub> = 25°C  |                         |      | 1.19 | V    |
|                   |                                              | I <sub>F</sub> = 240 A                                                              |                         |                         |      | 1.51 | V    |
|                   |                                              | I <sub>F</sub> = 120 A                                                              | T <sub>VJ</sub> = 150°C |                         |      | 1.06 | V    |
|                   |                                              | I <sub>F</sub> = 240 A                                                              |                         |                         |      | 1.48 | V    |
| I <sub>FAV</sub>  | average forward current                      | T <sub>C</sub> = 80°C                                                               | T <sub>VJ</sub> = 150°C |                         |      | 120  | A    |
|                   |                                              | rectangular      d = 0.5                                                            |                         |                         |      |      |      |
| V <sub>F0</sub>   | threshold voltage                            | } for power loss calculation only                                                   |                         | T <sub>VJ</sub> = 150°C |      | 0.65 | V    |
| r <sub>F</sub>    | slope resistance                             |                                                                                     |                         |                         |      | 3.4  | mΩ   |
| R <sub>thJC</sub> | thermal resistance junction to case          |                                                                                     |                         |                         |      | 0.4  | K/W  |
| R <sub>thCH</sub> | thermal resistance case to heatsink          |                                                                                     |                         |                         | 0.10 |      | K/W  |
| P <sub>tot</sub>  | total power dissipation                      | T <sub>C</sub> = 25°C                                                               |                         |                         |      | 310  | W    |
| I <sub>FSM</sub>  | max. forward surge current                   | t = 10 ms; (50 Hz), sine; V <sub>R</sub> = 0 V                                      |                         | T <sub>VJ</sub> = 45°C  |      | 1.20 | kA   |
| C <sub>J</sub>    | junction capacitance                         | V <sub>R</sub> = 100 V   f = 1 MHz                                                  |                         | T <sub>VJ</sub> = 25°C  | 328  |      | pF   |
| I <sub>RM</sub>   | max. reverse recovery current                | } I <sub>F</sub> = 120 A; V <sub>R</sub> = 100 V<br>-di <sub>F</sub> /dt = 200 A/μs |                         | T <sub>VJ</sub> = 25°C  | 6    |      | A    |
|                   |                                              |                                                                                     |                         | T <sub>VJ</sub> = 125°C | 16   |      | A    |
| t <sub>rr</sub>   | reverse recovery time                        |                                                                                     |                         | T <sub>VJ</sub> = 25°C  | 55   |      | ns   |
|                   |                                              |                                                                                     |                         | T <sub>VJ</sub> = 125°C | 85   |      | ns   |

preliminary

| Package SOT-227B (minibloc) |                                                              |                      |                                     | Ratings |      |      |      |
|-----------------------------|--------------------------------------------------------------|----------------------|-------------------------------------|---------|------|------|------|
| Symbol                      | Definition                                                   | Conditions           |                                     | min.    | typ. | max. | Unit |
| $I_{RMS}$                   | RMS current                                                  | per terminal         |                                     |         |      | 150  | A    |
| $T_{VJ}$                    | virtual junction temperature                                 |                      |                                     | -40     |      | 150  | °C   |
| $T_{op}$                    | operation temperature                                        |                      |                                     | -40     |      | 125  | °C   |
| $T_{stg}$                   | storage temperature                                          |                      |                                     | -40     |      | 150  | °C   |
| Weight                      |                                                              |                      |                                     |         | 30   |      | g    |
| $M_D$                       | mounting torque                                              |                      |                                     | 1.1     |      | 1.5  | Nm   |
| $M_T$                       | terminal torque                                              |                      |                                     | 1.1     |      | 1.5  | Nm   |
| $d_{Spp/App}$               | creepage distance on surface   striking distance through air | terminal to terminal | 10.5                                | 3.2     |      |      | mm   |
| $d_{Spb/Apb}$               |                                                              | terminal to backside | 8.6                                 | 6.8     |      |      | mm   |
| $V_{ISOL}$                  | isolation voltage                                            | t = 1 second         | 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA | 3000    |      |      | V    |
|                             |                                                              | t = 1 minute         |                                     | 2500    |      |      | V    |

## Product Marking



## Part number

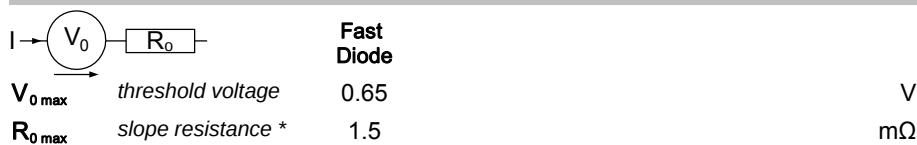
D = Diode  
 P = HiPerFRED  
 F = ultra fast  
 240 = Current Rating [A]  
 X = Parallel legs  
 200 = Reverse Voltage [V]  
 NA = SOT-227B (minibloc)

| Ordering | Part Number  | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|--------------|--------------------|---------------|----------|----------|
| Standard | DPF240X200NA | DPF240X200NA       | Tube          | 10       | 512342   |

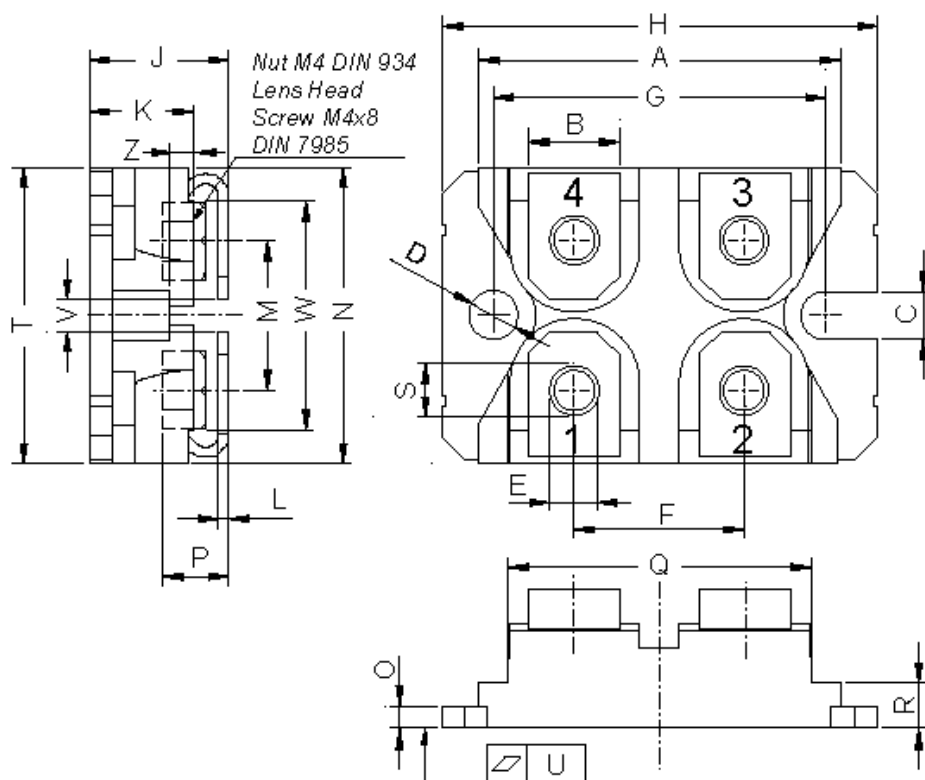
| Similar Part  | Package             | Voltage class |
|---------------|---------------------|---------------|
| DSEI2x121-02A | SOT-227B (minibloc) | 200           |

## Equivalent Circuits for Simulation

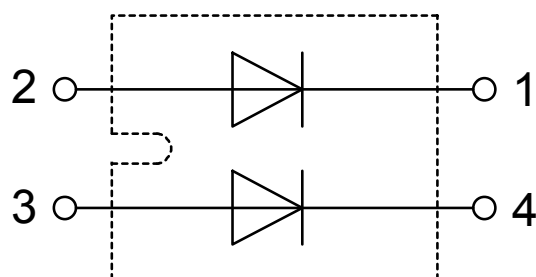
\* on die level

 $T_{VJ} = 150\text{ °C}$ 

### Outlines SOT-227B (minibloc)



| Dim. | Millimeter |       | Inches |       |
|------|------------|-------|--------|-------|
|      | min        | max   | min    | max   |
| A    | 31.50      | 31.88 | 1.240  | 1.255 |
| B    | 7.80       | 8.20  | 0.307  | 0.323 |
| C    | 4.09       | 4.29  | 0.161  | 0.169 |
| D    | 4.09       | 4.29  | 0.161  | 0.169 |
| E    | 4.09       | 4.29  | 0.161  | 0.169 |
| F    | 14.91      | 15.11 | 0.587  | 0.595 |
| G    | 30.12      | 30.30 | 1.186  | 1.193 |
| H    | 37.80      | 38.23 | 1.488  | 1.505 |
| J    | 11.68      | 12.22 | 0.460  | 0.481 |
| K    | 8.92       | 9.60  | 0.351  | 0.378 |
| L    | 0.74       | 0.84  | 0.029  | 0.033 |
| M    | 12.50      | 13.10 | 0.492  | 0.516 |
| N    | 25.15      | 25.42 | 0.990  | 1.001 |
| O    | 1.95       | 2.13  | 0.077  | 0.084 |
| P    | 4.95       | 6.20  | 0.195  | 0.244 |
| Q    | 26.54      | 26.90 | 1.045  | 1.059 |
| R    | 3.94       | 4.42  | 0.155  | 0.167 |
| S    | 4.55       | 4.85  | 0.179  | 0.191 |
| T    | 24.59      | 25.25 | 0.968  | 0.994 |
| U    | -0.05      | 0.10  | -0.002 | 0.004 |
| V    | 3.20       | 5.50  | 0.126  | 0.217 |
| W    | 19.81      | 21.08 | 0.780  | 0.830 |
| Z    | 2.50       | 2.70  | 0.098  | 0.106 |



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Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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